

	Class	Subclass
ISSUE CLASSIFICATION		

N

PATENT NUMBER

U.S. **UTILITY** Patent Application

O.I.P.E.

PATENT DATE

SCANNED

Q.A

APPLICATION NO. 09/917440	CONT/PRIOR	CLASS 257	SUBCLASS 296	ART UNIT 2811 2836	EXAMINER [Signature] Quinto
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PARTICIPANTS Zhigang Wang
Nian Yang
Yue-Song He

APPLICANTS

TITLE

N-Gate/N-Substrate or P-Gate/P-Substrate capacitor to characterize polysilicon gate depletion evaluation

PTO-2040
12/89**ISSUING CLASSIFICATION**[illegible]

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS		CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
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